

W-Band Power Amplifier, 75 to 110 GHz, 25 dB Gain, +15 dBm P_{1dB}

Description:

Model SBP-7531142515-1010-E1-WPC is a power amplifier with a typical small signal gain of 25 dB and a nominal output power of +15 dBm across the frequency range of 75 to 110 GHz. The DC power requirement for the amplifier is $+15 \text{ V}_{DC}/350 \text{ mA}$. The mechanical configuration offers an in line structure with WR-10 waveguides and UG-387/U-M anti-cocking flanges. Other port configurations, such as with 1 mm connectors or a



right angle structure with WR-10 waveguides, are also available under different model numbers.

Features:

- Full Waveguide Band Coverage
- High Gain
- **High Output Power**

Applications:

- Radar Systems
- **Communication Systems**
- **Test Equipment**

Electrical Specifications:

| Parameter | Minimum | Typical | Maximum |
|---------------------------|---------------------|--|---------------------|
| Frequency | 75 GHz | | 110 GHz |
| Gain | | 25 dB | |
| P _{1dB} | | +15 dBm | |
| P _{sat} | | +20 dBm | |
| P _{in} | | | +15 dBm |
| Input Return Loss | | 10 dB | |
| Output Return Loss | | 8 dB | |
| DC Voltage | +13 V _{DC} | +15 V _{DC} | +16 V _{DC} |
| DC Supply Current | e /// | 350 mA | |
| Specification Temperature | 7/1 | +25 °C | |
| Operating Temperature | 0 °C | The same of the sa | +50 °C |

Mechanical Specifications:

| Item | Specification | |
|---------------|---|--|
| Input Port | WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange | |
| Output Port | WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange | |
| Bias | Solder Pin | |
| Case Material | Aluminum | |
| Finish | Gold Plated | |
| Weight | 1.6 Oz | |
| Size | 1.10" (W) X 1.50" (L) X 0.75" (H) | |
| Outline | BG-SW-2-A | |



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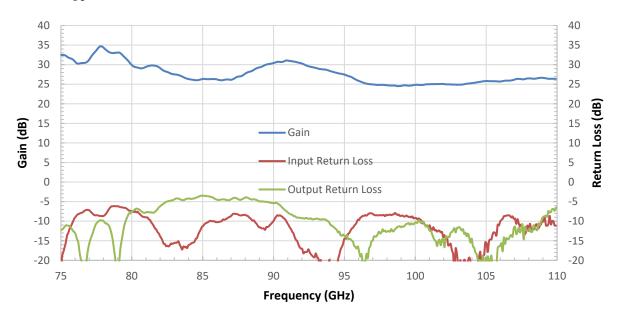
SAGE Millimeter, Inc.

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Test Data:

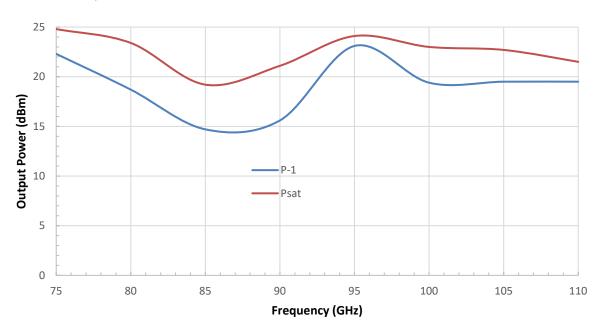
Gain and Return Loss vs. Frequency

Bias: +15 V_{DC}/348 mA



Output Power vs. Frequency

Bias: $+15 V_{DC}/348 \text{ mA}$ RFsat: +15 Vdc/480 mA





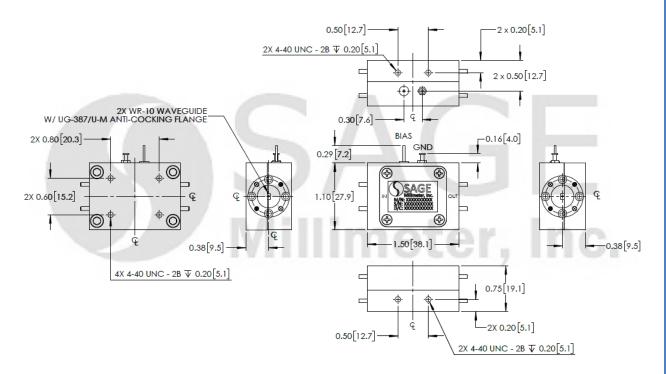
ESD

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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Eravant reserves the right to change the information presented without notice.
- Other mechanical configurations are available under different model numbers.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Any foreign objects in the waveguide will cause performance degradation and may damage the device.





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